NCE N-Channel Super Trench II Power MOSFET

Description

The NCEP045N10G uses **Super Trench II** technology that is uniquely optimized to provide the most efficient high frequency switching performance. Both conduction and switching power losses are minimized due to an extremely low combination of $R_{DS(ON)}$ and Q_g. This device is ideal for high-frequency switching and synchronous rectification.

Application

- DC/DC Converter
- Ideal for high-frequency switching and synchronous rectification

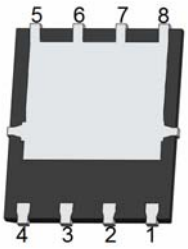
General Features

- V_{DS} =100V,I_D =125A
  $R_{DS(ON)}$=3.8mΩ (typical) @ V_{GS}=10V
- Excellent gate charge x $R_{DS(on)}$ product(FOM)
- Very low on-resistance $R_{DS(on)}$
- 150 °C operating temperature
- Pb-free lead plating

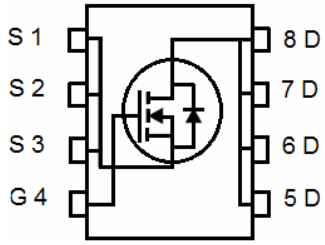
100% UIS TESTED!
100% ΔVds TESTED!

DFN 5X6

Top View



Bottom View



Schematic Diagram

Package Marking and Ordering Information

Device Marking	Device	Device Package	Reel Size	Tape width	Quantity
P045N10G	NCEP045N10G	DFN5X6-8L	-	-	-

Absolute Maximum Ratings (T_C=25℃unless otherwise noted)

Parameter	Symbol	Limit	Unit
Drain-Source Voltage	V_{DS}	100	V
Gate-Source Voltage	V_{GS}	±20	V
Drain Current-Continuous	I_D	125	A
Drain Current-Continuous(T_C=100℃)	I_D (100℃)	90	A
Pulsed Drain Current	I_{DM}	500	A
Maximum Power Dissipation	P_D	150	W
Derating factor		1.2	W/℃
Single pulse avalanche energy (Note 5)	E_{AS}	720	mJ
Operating Junction and Storage Temperature Range	T_J,T_{STG}	-55 To 150	℃

Thermal Characteristic

Thermal Resistance,Junction-to-Case (Note 2)	$R_{\theta JC}$	0.83	℃/W

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Electrical Characteristics (T_C=25℃unless otherwise noted)

Parameter	Symbol	Condition	Min	Typ	Max	Unit
Off Characteristics						
Drain-Source Breakdown Voltage	BV_{DSS}	V_{GS}=0V I_D=250μA	100		-	V
Zero Gate Voltage Drain Current	I_{DSS}	V_{DS}=100V,V_{GS}=0V	-	-	1	μA
Gate-Body Leakage Current	I_{GSS}	V_{GS}=±20V,V_{DS}=0V	-	-	±100	nA
On Characteristics (Note 3)						
Gate Threshold Voltage	$V_{GS(th)}$	V_{DS}=V_{GS},I_D=250μA	2	3	4	V
Drain-Source On-State Resistance	$R_{DS(ON)}$	V_{GS}=10V, I_D=65A	-	3.8	4.5	mΩ
Forward Transconductance	g_{FS}	V_{DS}=5V,I_D=65A		120	-	S
Dynamic Characteristics (Note4)						
Input Capacitance	C_{lss}	V_{DS}=50V,V_{GS}=0V, F=1.0MHz	-	5500	-	PF
Output Capacitance	C_{oss}		-	600	-	PF
Reverse Transfer Capacitance	C_{rss}		-	21	-	PF
Switching Characteristics (Note 4)						
Turn-on Delay Time	$t_{d(on)}$	V_{DD}=50V,I_D=65A, V_{GS}=10V,R_G=3Ω	-	21	-	nS
Turn-on Rise Time	t_r		-	13	-	nS
Turn-Off Delay Time	$t_{d(off)}$		-	40	-	nS
Turn-Off Fall Time	t_f		-	12	-	nS
Total Gate Charge	Q_g	V_{DS}=50V,I_D=65A, V_{GS}=10V	-	93	-	nC
Gate-Source Charge	Q_{gs}		-	21		nC
Gate-Drain Charge	Q_{gd}		-	27		nC
Drain-Source Diode Characteristics						
Diode Forward Voltage (Note 3)	V_{SD}	V_{GS}=0V,I_S=65A	-		1.2	V
Diode Forward Current (Note 2)	I_S		-	-	125	A
Reverse Recovery Time	t_{rr}	T_J = 25°C, I_F =65A di/dt = 100A/μs (Note3)	-	68	-	nS
Reverse Recovery Charge	Qrr		-	115	-	nC

Notes:

1. Repetitive Rating: Pulse width limited by maximum junction temperature.
2. Surface Mounted on FR4 Board, t ≤ 10 sec.
3. Pulse Test: Pulse Width ≤ 300μs, Duty Cycle ≤ 2%.
4. Guaranteed by design, not subject to production
5. EAS condition : Tj=25℃,V_{DD}=50V,V_G=10V,L=0.5mH,Rg=25Ω

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Typical Electrical and Thermal Characteristics

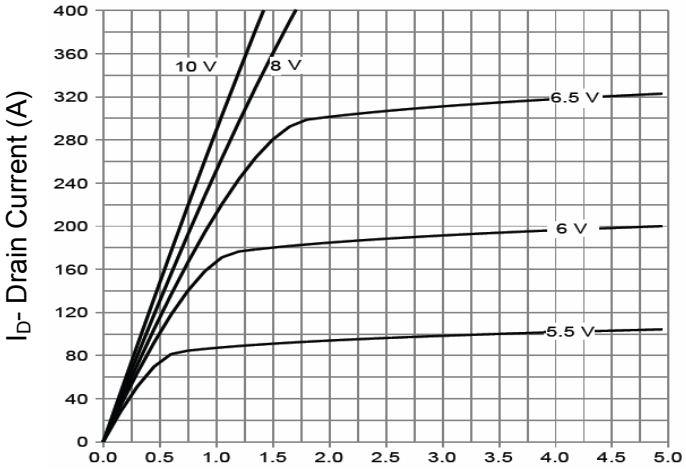

Figure 1 Output Characteristics

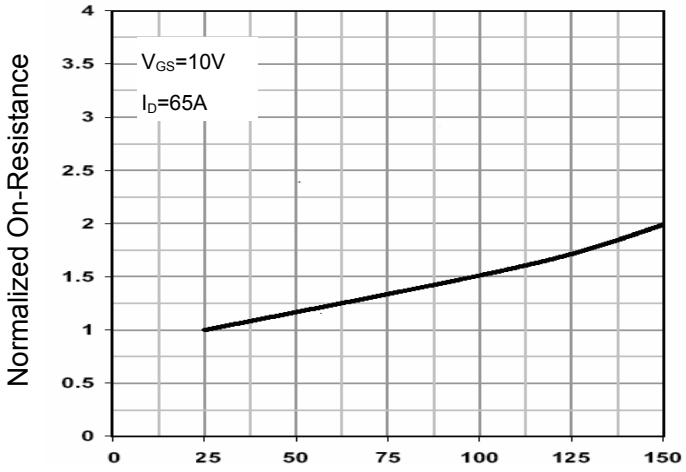

Figure 4 Rdson-Junction Temperature

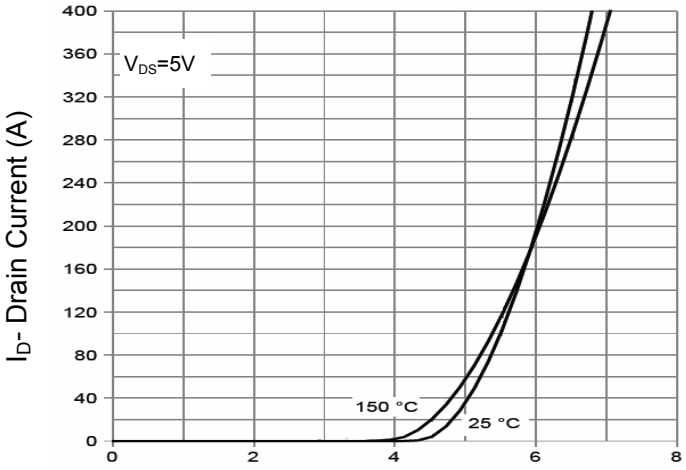

Figure 2 Transfer Characteristics

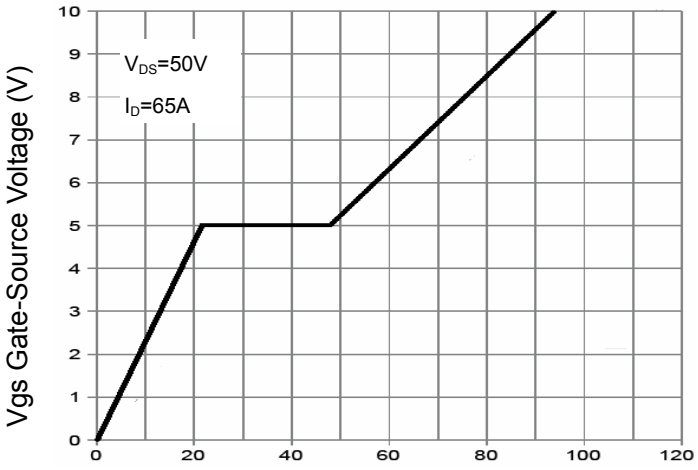

Figure 5 Gate Charge

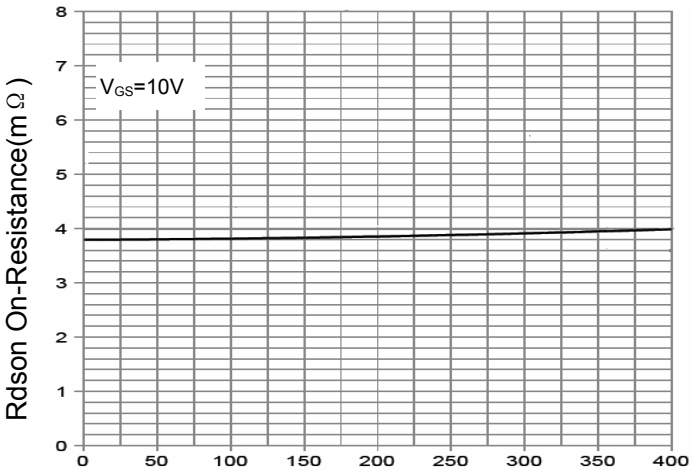

Figure 3 Rdson- Drain Current

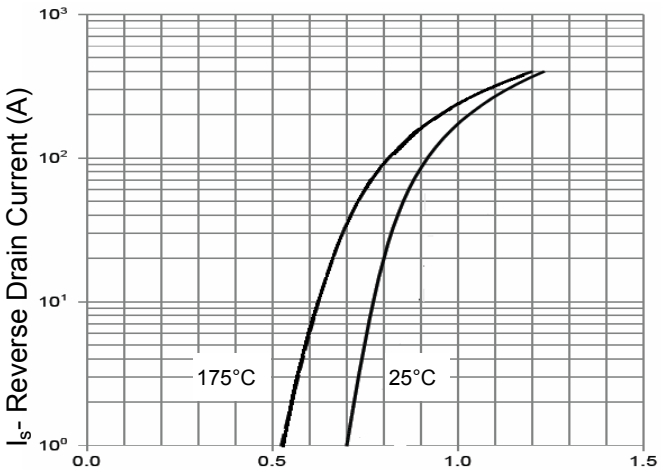

Figure 6 Source- Drain Diode Forward

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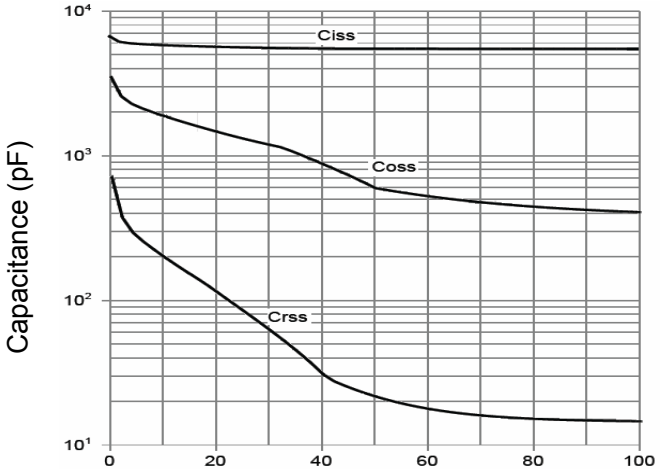

Figure 7 Capacitance vs Vds

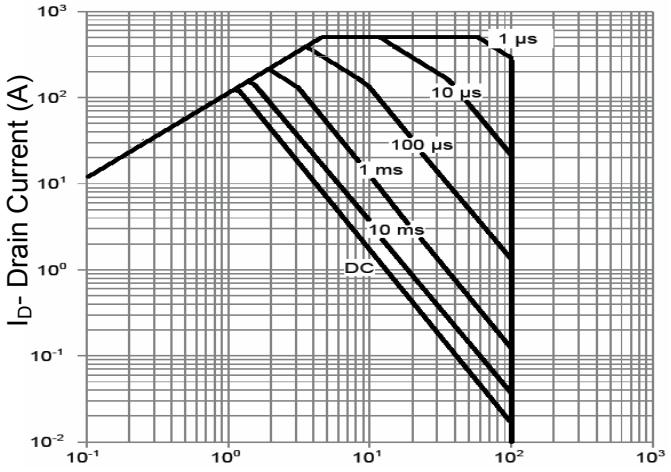

Figure 8 Safe Operation Area

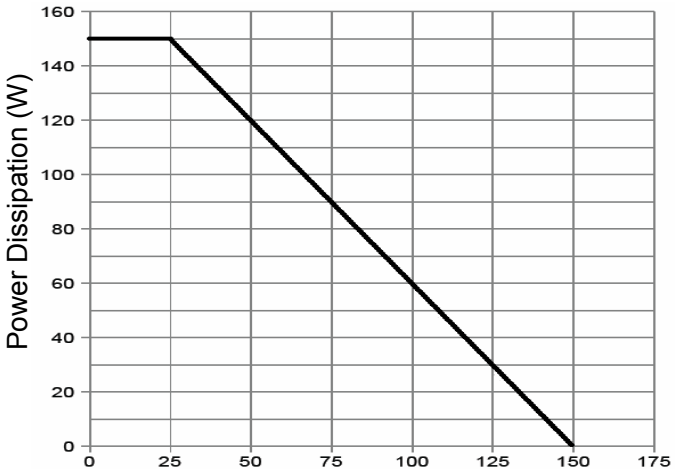

Figure 9 Power De-rating

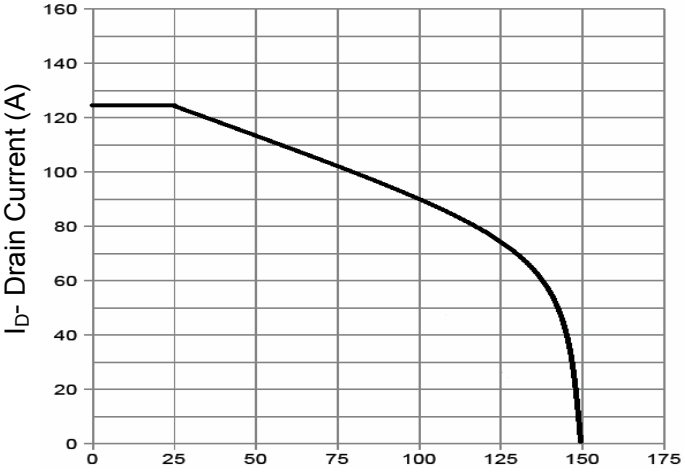

Figure 10 Current De-rating

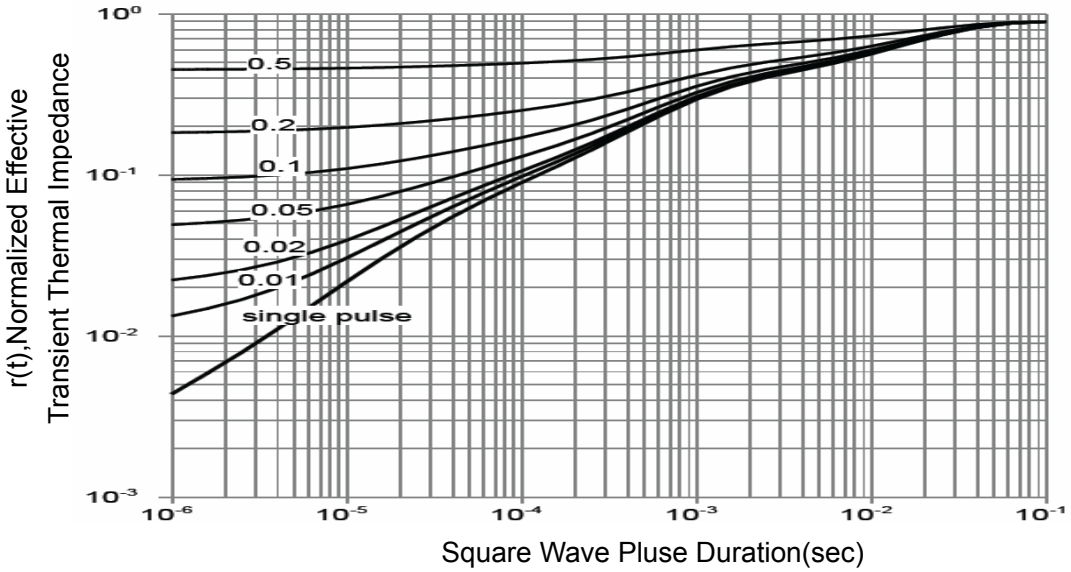

Figure 11 Normalized Maximum Transient Thermal Impedance

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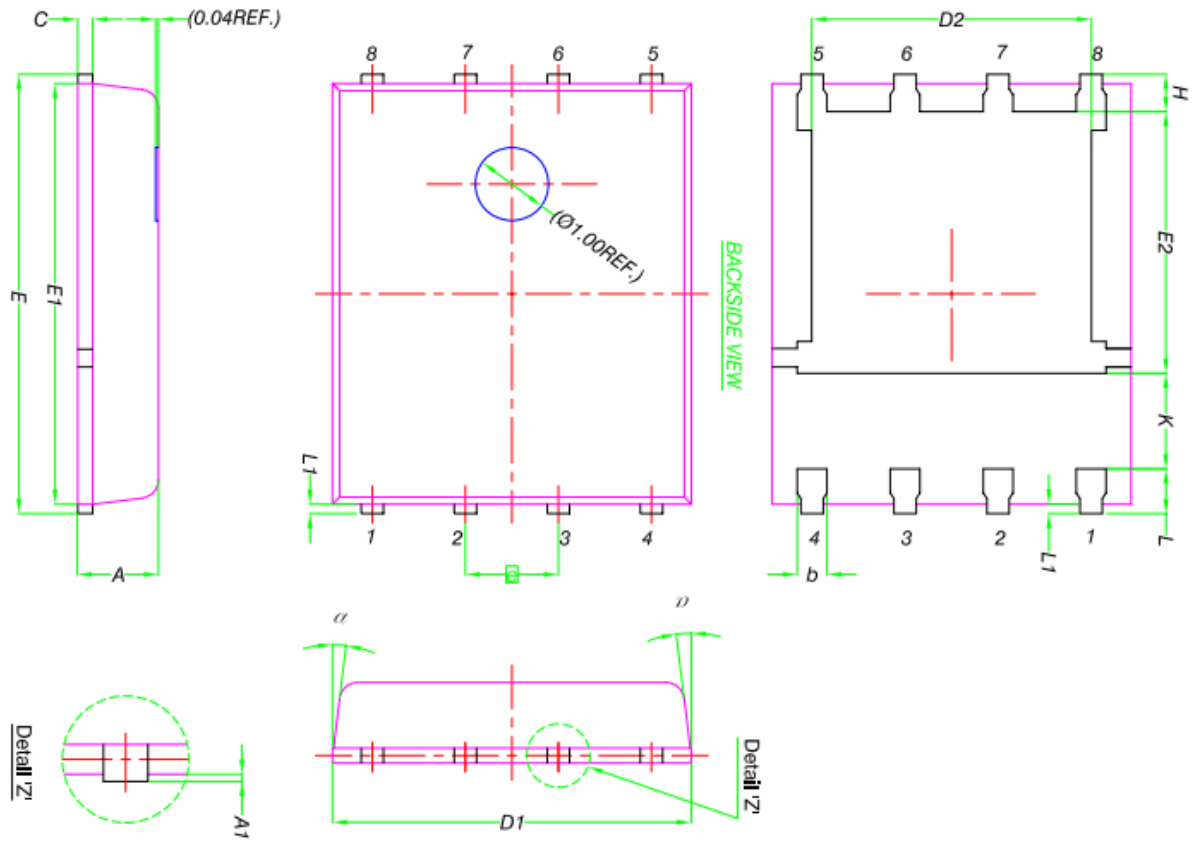
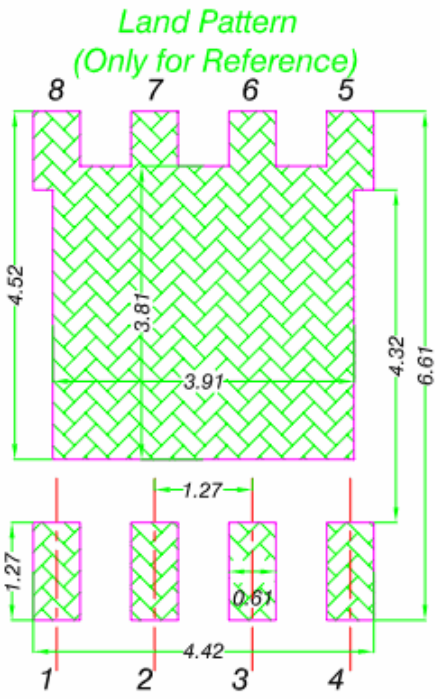
DFN5X6-8L Package Information



DIM.	MILLIMETERS		
	MIN.	NOM.	MAX.
A	0.90	1.00	1.10
A1	0	-	0.05
b	0.33	0.41	0.51
C	0.20	0.25	0.30
D1	4.80	4.90	5.00
D2	3.61	3.81	3.96
E	5.90	6.00	6.10
E1	5.70	5.75	5.80
E2	3.38	3.58	3.78
e	1.27 BSC		
H	0.41	0.51	0.61
K	1.10	-	-
L	0.51	0.61	0.71
L1	0.06	0.13	0.20
α	0°	-	12°



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